


**Field-induced spin reorientation in the Néel-type antiferromagnet MnPS<sub>3</sub>**Hui Han <sup>1,\*</sup>, Hong Lin <sup>1,\*</sup>, Wei Gan <sup>1</sup>, Ruichun Xiao <sup>1</sup>, Yucheng Liu <sup>1</sup>, Jiefeng Ye <sup>1</sup>, Limin Chen,<sup>2</sup>  
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Manipulation of spin orientation in magnetic material has been the focus of increasing research interest, as it brings fascinating perspectives with regard to the exploration of underlying magnetic interactions and the design of electronic devices. Here we report on the field-induced spin reorientation below Néel temperature in antiferromagnet MnPS<sub>3</sub>. The ferromagnetic ordering emerges in the antiferromagnetic phase in MnPS<sub>3</sub> at temperatures below  $\sim 34$  K with external magnetic fields up to  $\sim 2$  kOe. Such a coexistence of the ferromagnetic and antiferromagnetic phases is obtained in both perpendicular ( $H \perp ab$ ) and parallel ( $H // ab$ ) configurations, even with strong anisotropy. The  $H$ - $T$  phase diagram for MnPS<sub>3</sub> single crystal is further established with multiple magnetic phases being demonstrated. A phenomenological picture of the evolution of spin reorientation under external magnetic fields is proposed as physical insight into the rich magnetic properties of MnPS<sub>3</sub>. Our findings examine an exciting frontier in fundamental investigations of low-dimensional antiferromagnets and open a path towards the realization of conceptual electronic devices.

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Spin orientation plays a foundational role in determining the ground states of magnetic systems. Layered transition-metal phosphorous trichalcogenides  $MPX_3$  (where  $M = \text{Mn, Fe, etc.}$ ,  $X = \text{S, Se}$ ) with exceptional physical properties have provided a promising playground for physical insight into the relationship between spin orientation and magnetic ground states under various stimulations [1–6]. The spin orientation in  $MPX_3$  is conspired by subtle competition between multiple magnetic interactions, for example, the direct  $M$ - $M$  exchange interaction and indirect superexchange interaction between chalcogenide atoms within the intralayer and interlayer [7–13]. Mapping and engineering the spin orientation in  $MPX_3$  may open unforeseen opportunities for the exploration of underlying physics and the two-dimensional magnetic devices application [14–17].

As a representative two-dimensional antiferromagnet, the magnetic properties of MnPS<sub>3</sub> have been widely studied recently [18–21]. MnPS<sub>3</sub> possesses a layered structure with lattice constants  $a = 6.076$  Å,  $b = 10.524$  Å,  $c = 6.796$  Å,  $\alpha = \gamma = 90^\circ$ ,  $\beta = 107.35^\circ$  [19,22], forming a monoclinic crystal structure of  $C2/m$  space group, as shown in Figs. 1(a) and 1(b). The intralayer is covalent bonded, while the

interlayer is bonded by van der Waals force. Theoretical and experimental explorations have proved that the MnPS<sub>3</sub> features an antiferromagnetic property below Néel temperature of  $\sim 78$  K [20,21]. The nearest-neighbor interactions in each layer are antiferromagnetic, while the spin orientations are pointed towards the out-of- $ab$  plane, deviating from the normal direction of the  $ab$  plane by  $\sim 8^\circ$  [20], as shown in Fig. 1(c). Such small deviation of  $\sim 8^\circ$  in MnPS<sub>3</sub> offers new possibilities to engineer the spin orientations under multiple controls, such as intercalation [23,24], heterostructure [25,26], magnetic field [20,27], strain [28,29], and thickness [21,30,31], which could result in fascinating physical properties with implications in fundamental research and device design.

Here we report the manipulation of spin orientation in MnPS<sub>3</sub> single crystals below Néel temperature by external magnetic fields. The nonsynchronous evolution of the spin-up and spin-down components in MnPS<sub>3</sub> single crystals has led to the emergency of ferromagnetic (FM) ordering in the antiferromagnetic (AFM) phase below  $\sim 34$  K. A phenomenological view has been further proposed to physical insight into the spin orientation and rich magnetic properties under magnetic fields in antiferromagnet MnPS<sub>3</sub>.

**II. EXPERIMENT**

MnPS<sub>3</sub> single crystal was synthesized by the chemical vapor transport (CVT) method. Manganese powder (Aladdin,  $\geq 99.9\%$ ), phosphorus powder (Aladdin,  $\geq 98.5\%$ ), and

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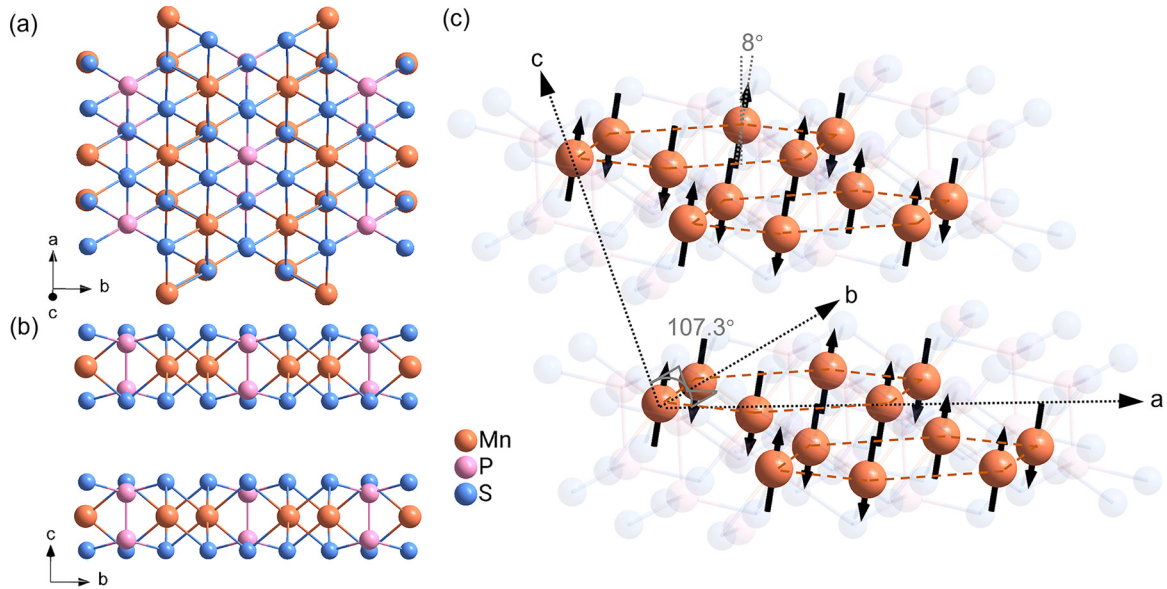


FIG. 1. Crystal and magnetic structure of  $\text{MnPS}_3$ : (a) top view and (b) side view of the  $\text{MnPS}_3$ ; (c) magnetic structure of  $\text{MnPS}_3$ .

sulfur powder (SCR,  $\geq 99.9\%$ ) were mixed in a stoichiometric ratio of 1:1:3 in the glovebox and sealed in a vacuum quartz tube. The tube was placed in a dual-temperature zone tubular furnace with the hot end at 700 K and cold end at 650 K for 3 days, and then slowly cooled to 650 K and 600 K for the hot and cold end, respectively, and kept for another 4 days. Finally, yellow transparent  $\text{MnPS}_3$  crystals were obtained.

X-ray diffraction (XRD) patterns were collected by a Rigaku D Max/Ultima IV diffractometer with monochromatized  $\text{Cu } K\alpha$  radiation ( $\lambda = 0.154 \text{ nm}$ ) to identify the crystal structure. The crystal morphology and elemental composition of  $\text{MnPS}_3$  were characterized by scanning electron microscopy (SEM) and energy-dispersive x-ray (EDX) spectroscopy. Magnetization measurements were carried out using a Quantum Design superconducting quantum interference device-vibrating sample magnetometer (SQUID-VSM). The no-overshoot mode was adopted to ensure a precise magnetic field. Temperature dependence of magnetic susceptibilities were measured in zero-field-cooling or field-cooling modes at selected magnetic fields. All isothermal magnetization curves were measured by cooling to the target temperature under zero magnetic field after the sample was warmed to 350 K and kept for several minutes.

### III. RESULTS AND DISCUSSION

Figure 2(a) shows the XRD pattern of the  $\text{MnPS}_3$ . The diffraction peaks are determined as  $(00l)$  of single-crystal  $\text{MnPS}_3$  with  $C2/m$  space group (standard PDF No. 00-33-0903). The layer spacing  $d$  is calculated to be  $6.535 \text{ \AA}$  from the  $(001)$  diffraction peak using Bragg's law, which is close to previous reports of  $6.5 \text{ \AA}$  [32]. No other diffraction peaks are observed, which validates the high-quality nature of single-crystal  $\text{MnPS}_3$ . The measured EDX spectroscopy of  $\text{MnPS}_3$  crystal [Fig. 2(b)] shows the calculated atomic ratio of grown  $\text{MnPS}_3$  crystal is  $\text{Mn} : \text{P} : \text{S} = 0.939 : 1.067 : 2.993$ , which is

close to the stoichiometry of  $\text{MnPS}_3$ . In addition, the Mn, P, and S elements are uniformly distributed, as demonstrated by the EDX mapping result in the inset of Fig. 2(b).

The temperature dependence of magnetic susceptibility ( $\chi$ - $T$ ) for single-crystal  $\text{MnPS}_3$  was investigated with a magnetic field of 200 Oe being applied perpendicular and parallel to the  $ab$  plane, respectively, as shown in Fig. 3. The  $\text{MnPS}_3$  exhibits multiple magnetic phase transitions as the temperature decreases from 300 to 10 K in the perpendicular configuration, *i.e.*,  $H \perp ab$  plane [Fig. 3(a)]. With temperature decreasing from 300 K, the magnetic susceptibility of  $\text{MnPS}_3$

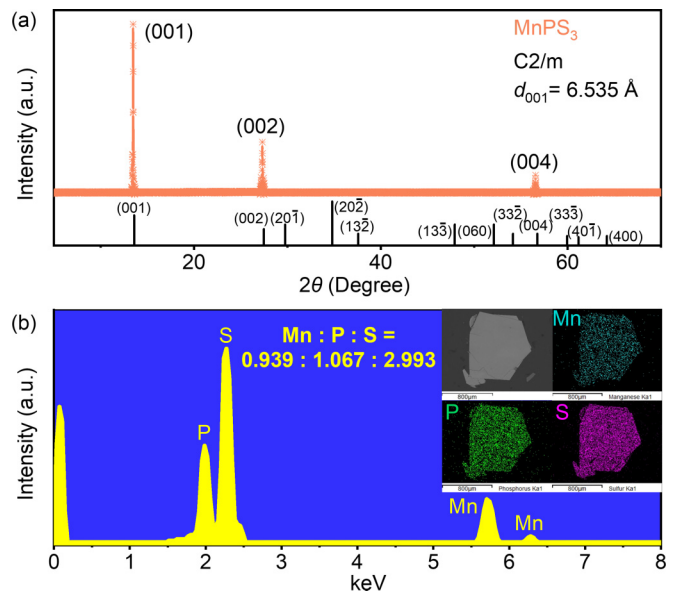


FIG. 2. (a) XRD pattern of  $\text{MnPS}_3$  with  $(00l)$  diffraction peaks indicated (orange curve). The bottom black lines are the diffraction peaks for  $\text{MnPS}_3$  with standard PDF No. 00-33-0903. (b) EDX spectroscopy of as-grown  $\text{MnPS}_3$ . Inset shows the morphology image and elements mapping of  $\text{MnPS}_3$  single crystal collected by SEM.

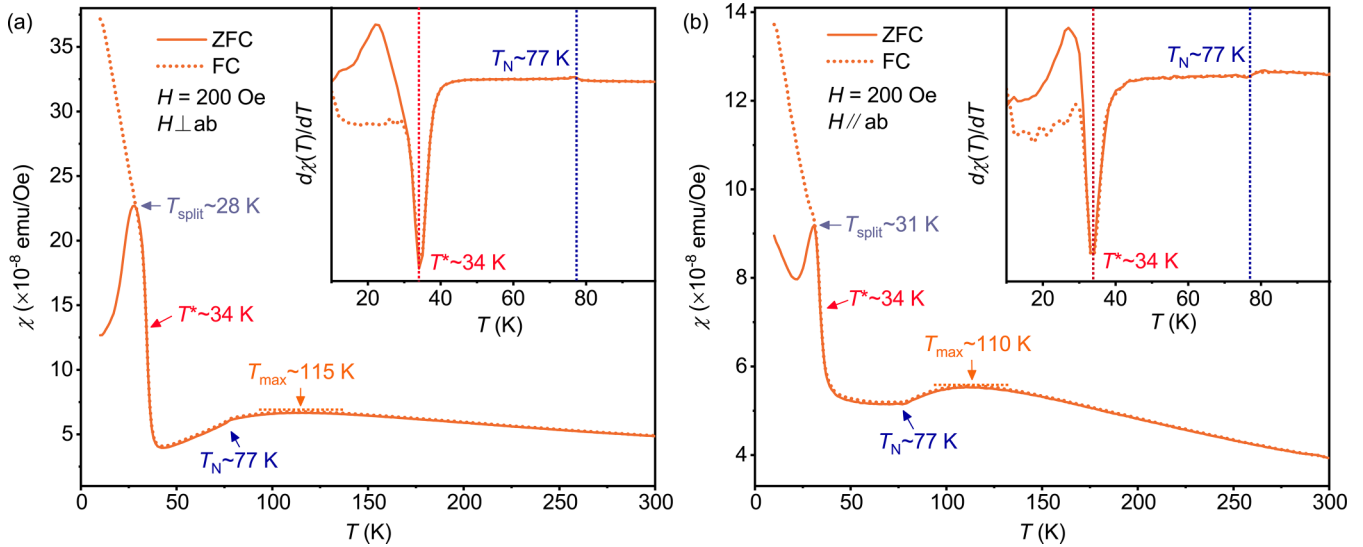


FIG. 3. Temperature dependence of magnetic susceptibility of MnPS<sub>3</sub> single crystal under ZFC (solid curve) and FC (dashed curve) with the  $H \perp ab$  plane (a) and  $H // ab$  plane (b), respectively. Insets show the differential curves  $[d\chi(T)/dT-T]$  with the characteristic temperatures  $T^*$  and  $T_N$  indicated.

gradually increases to its extremum value at  $T_{\max} \sim 115$  K [30] and then declines as the temperature further decreases, with a kink occurring at  $\sim 77$  K. The occurrence of a broad peak at  $T_{\max} \sim 115$  K suggests the emergency of AFM ordering in MnPS<sub>3</sub>, while the temperature for the kink at  $\sim 77$  K corresponds to the extremum value in the differential curve  $[d\chi(T)/dT-T]$  in the inset of Fig. 3(a) and is defined as Néel temperature,  $T_N$ . As temperature further decreases below  $\sim 40$  K, the magnetic susceptibility of MnPS<sub>3</sub> starts to increase rapidly, which is a signature of the emergency of FM ordering [20]. The FM transition temperature is determined to be  $T^* \sim 34$  K, corresponding to the extremum value of curve  $[d\chi(T)/dT-T]$  in the inset of Fig. 3(a). The splitting between the zero-field-cooling (ZFC, solid curve) and field-cooling (FC, dashed curve) curves occurs at  $T_{\text{split}} \sim 28$  K. Below the temperature, the magnetic susceptibility of MnPS<sub>3</sub> starts to decrease under ZFC and increases under FC measurements. This splitting between the ZFC and FC curves is probably related to the coexistence and competition between FM ordering and AFM ordering.

Similar multiple magnetic phase transitions are also observed in MnPS<sub>3</sub> in the parallel configuration, *i.e.*,  $H // ab$  plane, except that a very weak magnetic susceptibility upturn occurs below  $\sim 20$  K in the ZFC curve. This weak upturn may arise from various magnetic scatterings from defects, grain boundaries, etc. [5,33,34]. In addition, the magnetic susceptibility of MnPS<sub>3</sub> in the  $H // ab$  plane is smaller than that in the  $H \perp ab$  plane, indicating that MnPS<sub>3</sub> features strong magnetic anisotropy.

To gain physical insight into the phase transition at  $T^* \sim 34$  K, we further measured the temperature dependence of magnetic susceptibility of MnPS<sub>3</sub> at different magnetic fields for the  $H \perp ab$  plane and  $H // ab$  plane, respectively, as shown in Fig. 4. Under the  $H \perp ab$  plane, the magnetic susceptibility of MnPS<sub>3</sub> features a rapid increase at temperature below  $\sim 40$  K and a remarkable splitting between ZFC and FC curves at magnetic fields lower than 1 kOe [Fig. 4(a)]. The rapid

increase of magnetic susceptibility is indicative of the emergency of FM ordering, as discussed above. The FM transition temperature  $T^*$  is almost unchanged with increasing external magnetic fields, as indicated by the orange spheres in the inset of Fig. 4(a). It implies that FM ordering in MnPS<sub>3</sub> is robust at low magnetic fields. In contrast, the splitting between ZFC and FC curves is significantly suppressed. The characteristic temperature  $T_{\text{split}}$  gradually decreases with increasing magnetic fields and is invisible as the magnetic field increases to 1 kOe (light green curve), as indicated by the wine spheres in the inset of Fig. 4(a), suggesting that the coexistence of the FM phase and AFM phase in MnPS<sub>3</sub> is metastable.

However, as the magnetic field further increases above 2 kOe, the emerging FM ordering at  $\sim 34$  K disappears and the AFM ordering mainly dominates. Only a sharp decrease of magnetic susceptibility is observed at temperature below  $T_{\max}$  at 10 kOe (green curves) and 30 kOe (purple curves), as shown in Fig. 4(c). However, an upturn of magnetic susceptibility reoccurs at even higher magnetic field, for example, 50 kOe (light blue curves) and 70 kOe (dark blue curves) in Fig. 4(c). This upturn is related to the magnetic transition from AFM phase to forced ferromagnetic (FFM) phase under relatively high magnetic fields [29,32,35]. In addition, the magnitude of magnetic susceptibility of MnPS<sub>3</sub> experiences a nonmonotonous evolution with increasing magnetic fields. It first decreases as the magnetic field increases below 30 kOe, for example, the magnetic susceptibility is calculated to be  $\sim 9.7 \times 10^{-7}$  emu/Oe at 50 Oe and decreases by one order of magnitude to  $\sim 3 \times 10^{-8}$  emu/Oe at 30 kOe at 10 K in FC curves. Such suppression indicates that the FM ordering in MnPS<sub>3</sub> is getting weaker with increasing magnetic field. As the magnetic field further increases, the magnitude of magnetic susceptibility slightly increases to  $\sim 6.8 \times 10^{-8}$  emu/Oe at 70 kOe and 10 K, which corresponds to the formation of the FFM state. The evolution of magnetic susceptibility along with the increasing magnetic field of MnPS<sub>3</sub> in the

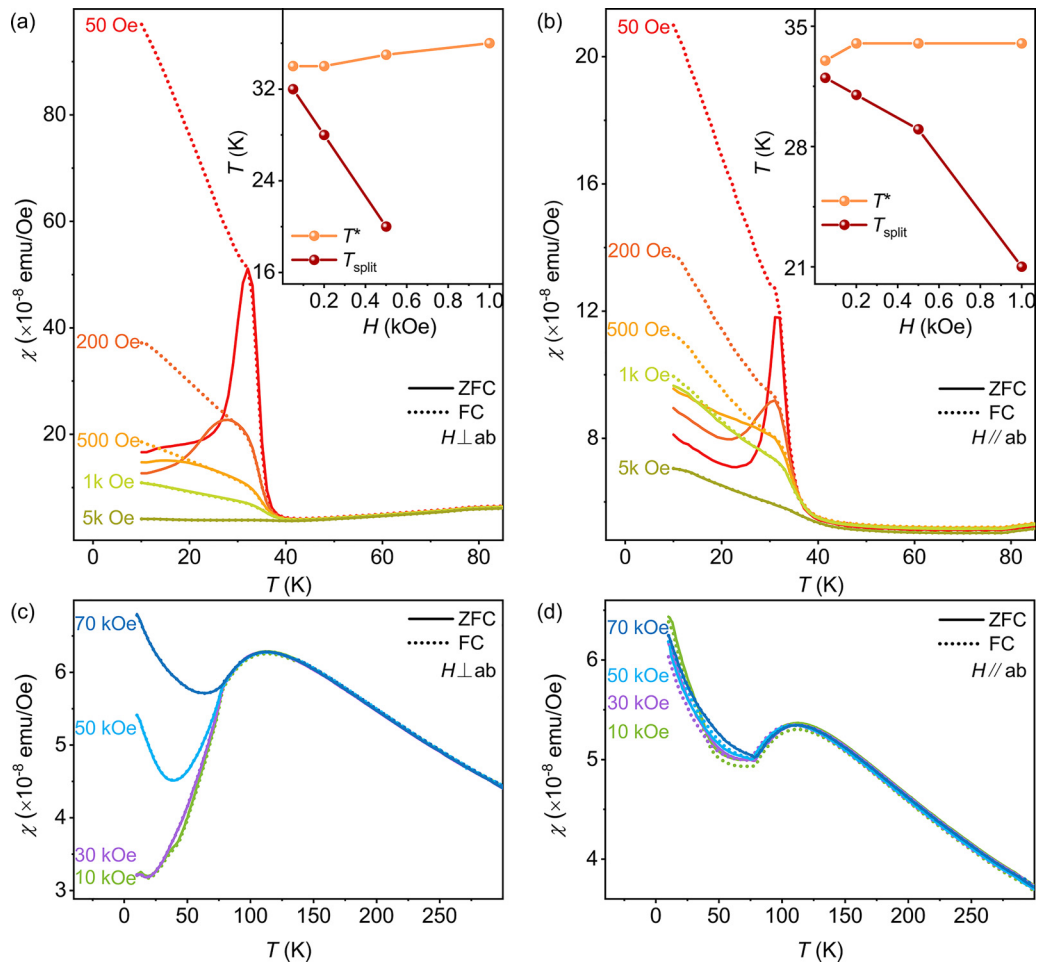


FIG. 4. Temperature dependence of magnetic susceptibility of MnPS<sub>3</sub> under different magnetic fields indicated for the  $H \perp ab$  plane (a), (c) and  $H // ab$  plane (b), (d), respectively. The solid and dashed curves represent the ZFC and FC measurements, respectively. The upper-right insets in (a) and (b) show the characteristic temperatures,  $T^*$  (orange spheres) and  $T_{\text{split}}$  (wine spheres), as a function of applied magnetic field.

$H // ab$  plane shares similar behaviors, as shown in Fig. 4(b) for the low magnetic field and Fig. 4(d) for the high magnetic field. The critical magnetic field for formation of the FFM state in the  $H // ab$  plane is estimated to be  $\sim 10$  kOe [Fig. 4(d)], in which an evident magnetic susceptibility upturn occurs below  $T_N$ . This critical magnetic field in the  $H // ab$  plane is smaller than that in the  $H \perp ab$  plane of  $\sim 50$  kOe, which may relate to the magnetic structure of MnPS<sub>3</sub>, with an easy axis being aligned roughly along the out-of- $ab$  plane [Fig. 1(c)].

Isothermal magnetization ( $M$ - $H$ ) curves for MnPS<sub>3</sub> at selected temperatures of 10 K, 35 K, and 100 K for the  $H \perp ab$  plane and  $H // ab$  plane are shown in Fig. 5. The MnPS<sub>3</sub> features a distinctive anisotropic property. For the  $H \perp ab$  plane in Fig. 5(a), a linear dependence of  $M$  versus  $H$  is observed at 100 K (blue curve), suggesting the formation of a paramagnetic (PM) state in MnPS<sub>3</sub>. However, an evident upturn occurs at a magnetic field of  $\sim 45$  kOe and  $\sim 35$  kOe as the temperature further cools to 35 K (red curve) and 10 K (black curve), respectively. The upturn in isothermal magnetization above a critical magnetic field is most likely due to the spin-flop transition in MnPS<sub>3</sub>, which indicates the easy axis of MnPS<sub>3</sub> is roughly normal to the  $ab$  plane and is consistent

with previous studies [32,36,37]. No magnetization saturation is observed for MnPS<sub>3</sub> with the  $H \perp ab$  plane, even with magnetic fields increasing to 70 kOe. In addition, an evident hysteresis loop with coercive field of  $\sim 115$  Oe is observed in MnPS<sub>3</sub> at 10 K with the  $H \perp ab$  plane, as indicated by the black curve in the zoom-in view in Fig. 5(b), and smears out as temperature increases above 35 K [red curve for 35 K and blue curve for 100 K in Fig. 5(b)]. The occurrence of a hysteresis loop in the  $M$ - $H$  curves is indicative of the formation of FM ordering, which coincides with the observed magnetic phase transition at  $T^* \sim 34$  K in the  $\chi$ - $T$  curves in Figs. 3(a) and 4(a). Moreover, the hysteresis loop exhibits a slight shrink in the vicinity of zero magnetic moment with a very small coercive field of  $\sim 115$  Oe, which suggests the FM ordering is weak and probably coexisted with AFM ordering. This also coincides with the splitting of the ZFC and FC curves at low temperatures, while for the  $H // ab$  plane the  $M$ - $H$  curves show linear behaviors at all temperatures of 10, 35, and 100 K, as shown in Fig. 5(c). The zoom-in view of Fig. 5(d) shows an unremarkable hysteresis loop at 10 K (black curve). Such hysteresis loops may arise from instrumental error or the relatively weaker FM ordering existing along the  $ab$  plane than that normal to the  $ab$  plane.

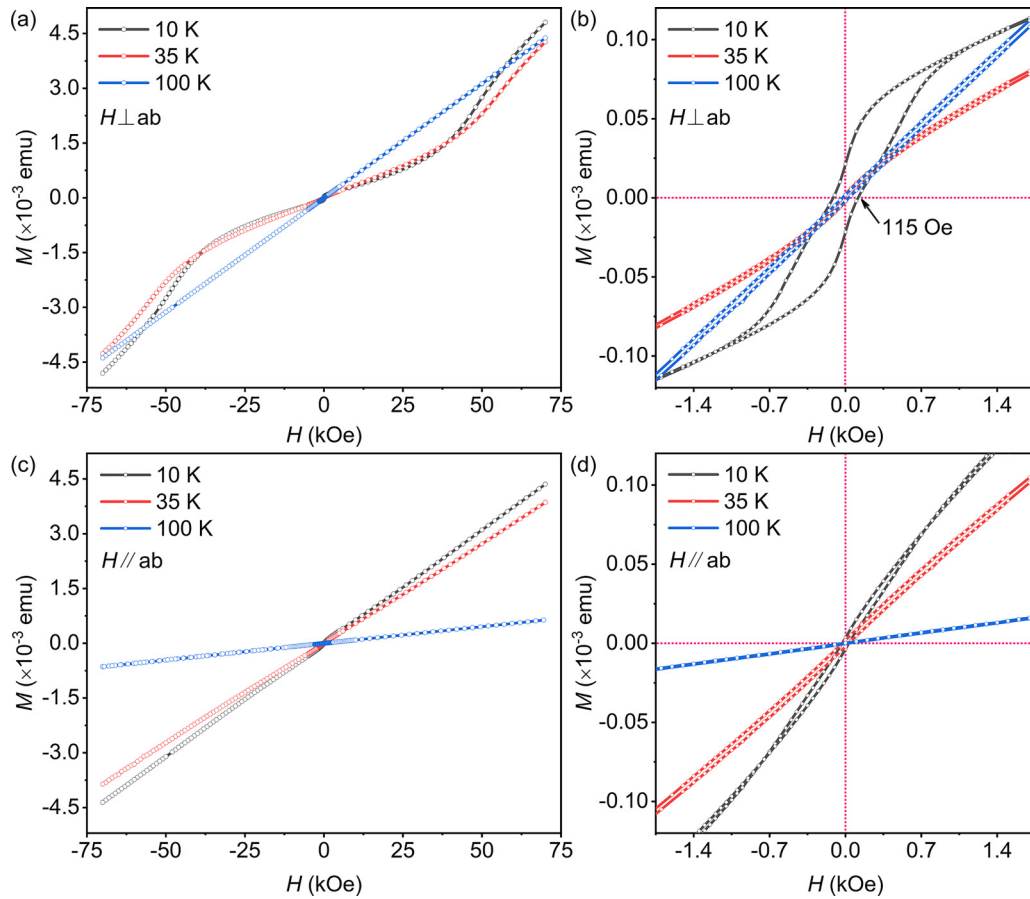


FIG. 5.  $M$ - $H$  curves for MnPS<sub>3</sub> at different temperatures indicated (10 K, 35 K, 100 K) for the  $H \perp ab$  plane (a) and  $H // ab$  plane (c). Zoom-in view of  $M$ - $H$  curves at low magnetic fields for  $H \perp ab$  plane (b) and  $H // ab$  plane (d), respectively.

Further increasing temperature above 35 K (red curve for 35 K and blue curve for 100 K) causes the hysteresis loop to be invisible.

Figure 6 shows the established magnetic phase diagram ( $H$ - $T$ ) of MnPS<sub>3</sub> based on the measured  $\chi$ - $T$  and  $M$ - $H$

curves at low magnetic fields ( $H < 5$  kOe) for  $H \perp ab$  plane and  $H // ab$  plane, respectively. At magnetic fields lower than 2 kOe, the magnetic phase diagram is divided into four different regions, which sequentially transition from the PM phase, the coexisting AFM phase and PM phase (AFM & PM), the

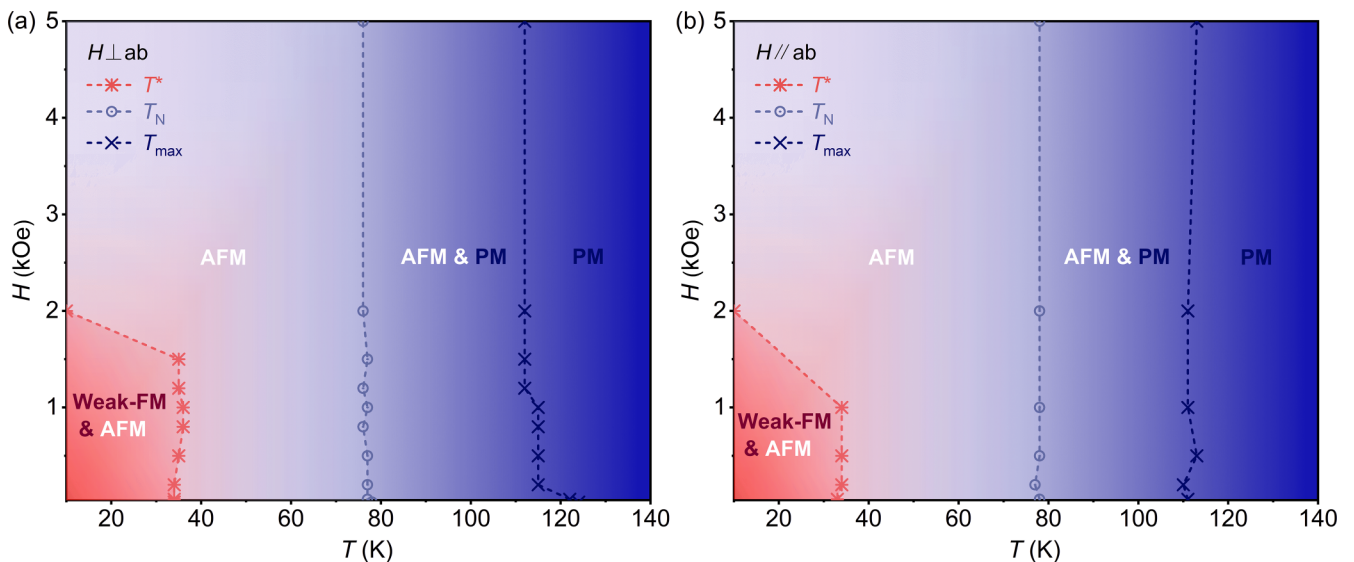


FIG. 6.  $H$ - $T$  phase diagram of MnPS<sub>3</sub> for the  $H \perp ab$  plane (a) and  $H // ab$  plane (b), respectively.

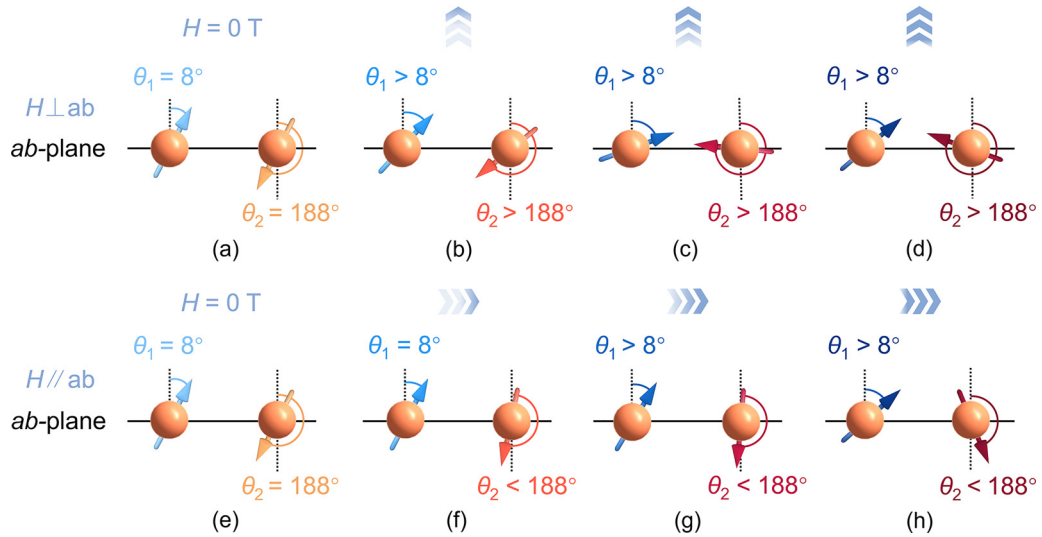


FIG. 7. Schematic diagram of evolution of spin orientation along external magnetic field for the  $H \perp ab$  plane (a)–(d) and  $H // ab$  plane (e)–(h), respectively. The direction and filling gradient of the top blue arrows indicate the magnetic field orientation and strength, respectively.

AFM phase, and the coexisting weak-FM phase and AFM phase (weak-FM & AFM) along with decreasing temperature from 140 to 10 K, while at the intermediate magnetic fields region, *i.e.*,  $2 \text{ kOe} < H < 5 \text{ kOe}$ , the coexisting weak-FM & AFM phases disappear with only three magnetic phases being left, as discussed qualitatively below. A similar magnetic phase diagram is also established for  $H // ab$  plane, as shown in Fig. 6(b).

Figure 7 depicts a simplified schematic diagram of the evolution of spin orientations under the  $H \perp ab$  plane [Figs. 7(a)–7(d)] and  $H // ab$  plane [Figs. 7(e)–7(h)] configurations below  $T^*$ . At the initial stage with  $H = 0 \text{ Oe}$ , the spins of neighboring Mn atoms are antiparallel aligned with spin-up (or spin-down) orientation of  $\theta_1 \sim 8^\circ$  (or  $\theta_2 \sim 188^\circ$ ) from the normal direction of the  $ab$  plane [Fig. 7(a)], which is the magnetic ground state proved by neutron diffraction measurements [20]. When applying a weak perpendicular magnetic field, the spin-up and spin-down components tend to rotate towards the  $ab$  plane with  $\theta_1 > 8^\circ$  and  $\theta_2 > 188^\circ$ , as indicated by Fig. 7(b). Such rotation behavior is believed to be a consequence of the competition between the external magnetic field and magnetic anisotropy of MnPS<sub>3</sub>. The antiparallel alignment between the spin-up and spin-down components is roughly maintained at small external magnetic field due to the magnetic anisotropy field and strong AFM interaction between the nearest Mn ions in MnPS<sub>3</sub> [10,36,38–40]. However, the rotation of the spin-up and spin-down components is nonsynchronized, which results in the existence of net magnetization, as evidenced from the occurrence of FM ordering from the  $\chi$ - $T$  curves in Figs. 3(a) and 4(a) at temperatures below  $T^* \sim 34 \text{ K}$  and the emergency of the narrow hysteresis loop in the  $M$ - $H$  curve at 10 K in Fig. 5(b). As the strength of the perpendicular magnetic field increases, the spin-up and spin-down components are gradually aligned parallel to the  $ab$  plane, as shown in Fig. 7(c). This corresponds to the spin-flop process occurring at critical magnetic field, as demonstrated from the  $M$ - $H$  curves in Fig. 5(a). In addition, the AFM ordering dominates under this situation,

which coincides with the experimental measured  $\chi$ - $T$  curves collected at  $H = 10 \text{ kOe}$  and  $30 \text{ kOe}$  in Fig. 4(c). Further increasing perpendicular magnetic fields, both the spin-up and spin-down components are rotated towards the direction of the external magnetic fields with opposite rotation direction, *i.e.*, counterclockwise for the spin-up component and clockwise for the spin-down component, as demonstrated in Fig. 7(d). This relates to the emergency of the FFM state, which is consistent with experimental measurements of the  $\chi$ - $T$  curves in Fig. 4(c) with magnetic field above 50 kOe. It is noted that reversal of spin direction for the spin-down component occurs with increasing perpendicular magnetic field, as illustrated in Figs. 7(c) and 7(d). Moreover, the nonsaturation behavior in the  $M$ - $H$  curves of MnPS<sub>3</sub> [Fig. 5(a)] suggests that the spins are not well aligned parallel to the external field, even at high magnetic fields of 70 kOe [Fig. 7(d)].

The evolution of spin orientation along with parallel magnetic field is depicted in Figs. 7(e)–7(h). Figure 7(e) is the magnetic ground state with the same configuration in Fig. 7(a). With increasing parallel magnetic field, the spin-up component and spin-down component are both rotated in the direction of the external magnetic fields [Figs. 7(f)–7(h)]. The rotation direction of the spin-up and spin-down components is opposite one another, *i.e.*, clockwise for the spin-up component and counterclockwise for the spin-down component. The nonsynchronized rotation between the spin-up and spin-down components at small parallel magnetic field may give rise to the occurrence of weak FM ordering [Figs. 7(f) and 7(g)], as evidenced from the  $\chi$ - $T$  curves in Figs. 3(b) and 4(b). With further increasing strength of parallel magnetic fields, the spin-down component gradually crosses the normal line of the  $ab$  plane [Fig. 7(h)], which may result in the emergency of an FFM state in MnPS<sub>3</sub>, as evidenced from the measured  $\chi$ - $T$  curves in Fig. 4(d). It should be noted that although the suspected phenomenological picture of the evolution of spin rotation may account for most of the intriguing observations in our MnPS<sub>3</sub> system, the quest for further

theoretical and experimental investigations have remained a demanding challenge.

#### IV. CONCLUSION

We have systematically studied the magnetic properties of antiferromagnet MnPS<sub>3</sub>. A weak FM ordering is observed at temperatures below  $T^* \sim 34$  K at magnetic fields lower than 2 kOe in both the  $H \perp ab$  plane and  $H // ab$  plane configurations. The splitting between the ZFC and FC curves further suggests the weak short-range FM ordering is metastable and coexists with AFM ordering. In addition, the weak FM ordering is suppressed with increasing external magnetic fields. The  $H$ - $T$  phase diagram for MnPS<sub>3</sub> is further established with various magnetic phases being obtained, including the coexisting weak-FM phase and AFM phase, the AFM phase, the coexisting AFM phase and PM phase, and the PM phase. A phenomenological picture of the evolution of spin re-

orientation under external magnetic fields has been further proposed as physical insight into the rich magnetic properties of antiferromagnet MnPS<sub>3</sub> qualitatively. Our findings may stimulate new perspectives for fundamental investigations of low-dimensional antiferromagnets and afford the realization of proof-of-concept devices with potential practical applications in advanced integrated circuits.

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